

General description

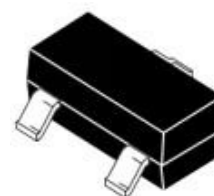
These dual monolithic silicon surge protection diodes are designed for applications requiring transient overvoltage protection capability. They are intended for use in voltage and ESD sensitive equipment. as computers, printers, business machines, communication systems, medical equipment and other applications. Their dual junction common anode design protects two separate lines using only one package. These devices are ideal for situations where board space is at a premium.

Features and benefits

- 2 Unidirectional transil functions
- Reverse stand-off voltage: 3.3V Max
- Low leakage current: nA Level
- Response time is typically < 1 ns
- ESD Protection: 15kV(air)/ 8kV(contact)
(IEC61000-4-2)

Application information

- Computers
- Printers
- Communication systems
- Cellular Handsets and Accessories
- Portable Electronis
- Industrial Controls
- Set-Top Box

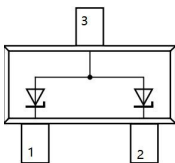


SOT23

Ordering information

Device	Package	Marking	Packaging
ESDM03	SOT23	M03	3000/Tape & Reel

Schematic & Pin configuration

Simplified outline and symbol	Pinning
	PIN1 cathode 1 PIN2 cathode 2 PIN3 common anode

Maximum Ratings (T_{OP} = 25 °C, unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (tp = 8/20μs)	P _{PPM}	160	W
Peak Pulse Current(tp = 8/20μs)	I _{PPM}	11	A
Maximum lead temperature for soldering during 10s	T _L	260	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C
Operating Temperature Range	T _{OP}	-40 to +125	°C
Maximum junction temperature	T _j	150	°C
ESD voltage IEC 61000-4-2 (air discharge)	V _{ESD}	15	kV
ESD voltage IEC 61000-4-2 (contact discharge)	V _{ESD}	8	kV

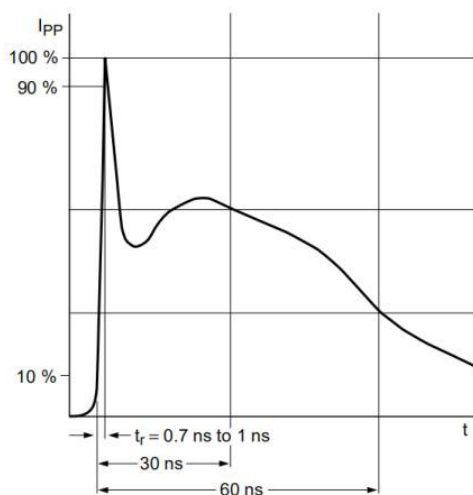
Electrical Characteristics (T_{OP} = 25 °C, unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Condition
Reverse Working Voltage	V _{RWM}	--	--	3.3	V	
Breakdown Voltage	V _{BR}	4.5	--	--	V	I _T =1mA
Leakage Current I _{Leak}	I _R	--	--	100	nA	V _{RWM} =3.3V
Clamping Voltage	V _C	--	--	14.0	V	I _{pp} =11A, T _p =8/20μs
Junction Capacitance	C _J	--	--	100	pF	V _R =0V, f=1MHz (Pin 1 or 2 to 3)
		--	--	50	pF	V _R =0V, f=1MHz (Pin 1 to P2 and 2 to 1)

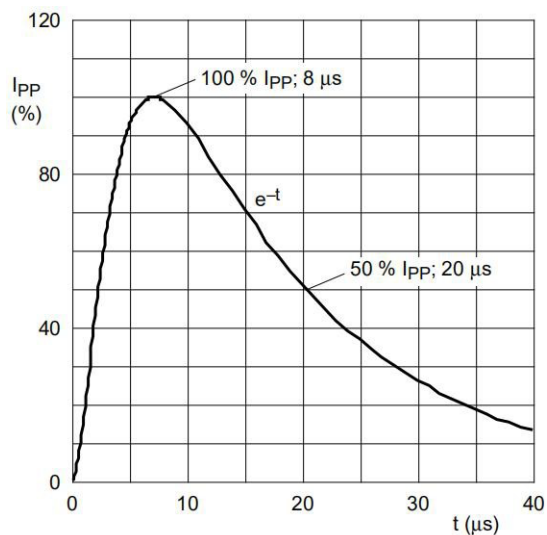
ESDM03

2-Line Unidirectional ESD Protection Diode

Typical Characteristics



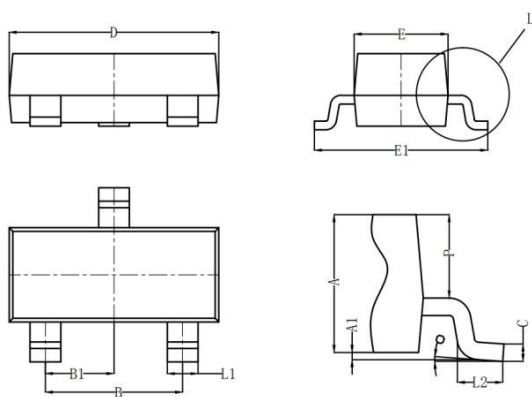
IEC61000-4-2 Waveform



IEC 61000-4-5 Waveform(8/20μs pulse)

Package Outline Dimensions

SOT23



Symbol	Dimensions (mm)		
	Min	Typ	Max
A	0.900	1.000	1.1100
A1	0.000	0.050	0.100
L1	0.350	0.400	0.500
C	0.100	0.110	0.120
D	2.800	2.900	3.000
E	1.250	1.300	1.350
E1	2.250	2.400	2.550
B	1.800	1.900	2.000
B1	0.950 Typ		
L2	0.200	0.350	0.450
P	0.550	0.575	0.600